

## **Transient Voltage Suppressor**

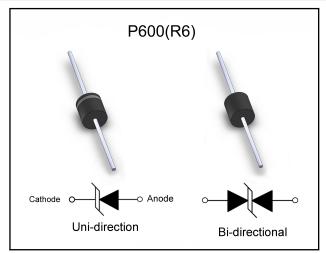
#### **Features**

- · Excellent clamping capability
- · Low leakage current
- · Low capacitance
- · High surge capability
- · Glass passivated chip
- · Epoxy resin package
- · Will not fatigue
- RoHS Compliant
- Meets ISO7637-2、16750-2 surge specifiation
- ISO 7637-2 P5a:

12V System (65-87V 0.5-4Ω 40-400ms)

24V System (123-174V 1-8Ω 100-350ms)

# **Package**



### **Mechanical Characteristics**

· Package: P600 plastic package

· Lead Finish: Matte Tin

· Case Material: Epoxy Molding Compound

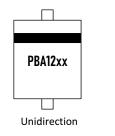
• UL Flammability Classification Rating 94V-0

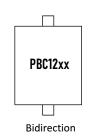
• Moisture Sensitivity: Level 1 per J-STD-020

### **Applications**

- · Auto powers system
- · Can-bus
- · ABS powers
- · Automotive instrument
- · Car GPS

### **Making Code**





## **Summary of Packing Options**

Package	Packing Description	Packing Quantity	Industry Standard	
P600	Tape/Box,Box	300	EIA-481-1	
P000	Tape/Reel,13" reel	800	EIA-481-1	

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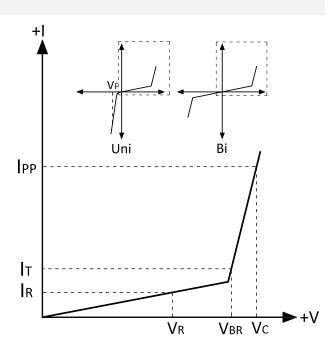




## **Transient Voltage Suppressor**

#### **Electrical Parameters**

Parameter	Definition
CJ	Junction Capacitance - typical capacitance
	measured with 0V or V <sub>R</sub> bias
l	Peak Pulse Current - maximum rated peak
I <sub>PP</sub>	impulse current
V <sub>C</sub>	Clamping Voltage - Peak voltage measured
٧C	across the suppressor at a specified lppm
$V_{BR}$	Breakdown Voltage - Maximum voltage that flows
<b>V</b> BR	though the TVS at a specified test current $(I_T)$
I_	Leakage Current - maximum peak off-state
I <sub>R</sub>	current measured at V <sub>R</sub>
$V_R$	Peak Off-state Voltage - maximum voltage
۷R	that can be applied while maintaining off state



## Absolute Maximum Ratings (T<sub>A</sub>=+25°C, unless otherwise noted)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation (Note1)	P <sub>PPM</sub>	12000	W
Steady State Power Dissipation (Note2)	P <sub>D</sub>	8	W
Peak Forward Surge Current (Note3)	I <sub>FSM</sub>	400	А
Maximum Instantaneous Forward Voltage at 100A (Note4)	$V_{FM}$	5	V
Typical Thermal Resistance Junction to Lead	R <sub>0JL</sub>	8	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	40	°C/W
Operating Temperature Range	TJ	-55 to 175	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to 175	°C

#### Notes:

- (1) Non-repetitive current pulse, 10/1000us Waveform.
- (2) Infinite HeatSink at T<sub>L</sub> =75°C,at 0.375"(9.5mm) lead length, P.C.B. mounted.
- (3) Measured on 8.3ms single half sine wave or equivalent square wave, duty cycle=4 perminute maximum.
- (4) For Unidirectional Only,  $V_{FW}$ <3.5V for  $V_{BR}$  ≤200V and  $V_{FM}$ <5.0V for  $V_{BR}$ ≥201V.





# **Transient Voltage Suppressor**

Electrical Characteristics (T<sub>A</sub>=+25°C, unless otherwise noted)

Part Number	Part Number	Reverse Stand-Off Votage V <sub>R</sub>	Volt	kdown tage k@l <sub>T</sub>	Test Current I <sub>T</sub>	Maximum Clamping Voltage V <sub>C</sub> @ I <sub>IPP</sub>	Maximum Peak Pulse Current I <sub>IPP</sub>	Maximun Reverse Leakage I <sub>R</sub> @V <sub>R</sub>
(Uni)	(Bi)	(V)	Min.(V)	Max.(V)	(mA)	(V)	(A)	(uA)
12KP30A	12KP30CA	30	33.3	36.8	5	48.4	247	5
12KP33A	12KP33CA	33	36.7	40.6	5	53.3	225	5
12KP36A	12KP36CA	36	40.0	44.2	5	58.1	206	5
12KP40A	12KP40CA	40	44.4	49.1	5	64.5	186	5
12KP43A	12KP43CA	43	47.8	52.8	5	69.4	172	5
12KP45A	12KP45CA	45	50.0	55.3	5	72.7	165	5
12KP48A	12KP48CA	48	53.3	58.9	5	77.4	155	5





# **Transient Voltage Suppressor**

Ratings and Characteristic Curves (T<sub>A</sub>=+25°C, unless otherwise noted)

Figure 1: Peak Pulse Power Rating



Figure 2: Pulse Derating Curve

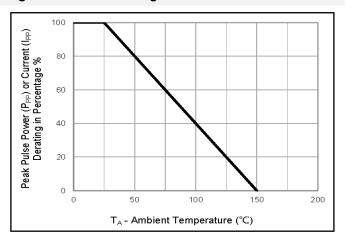
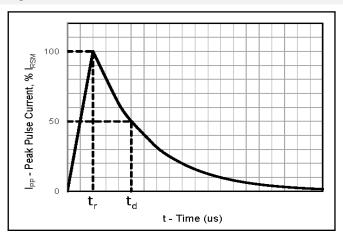


Figure 3: Pulse Waveform



**Figure 4: Typical Junction Capacitance** 

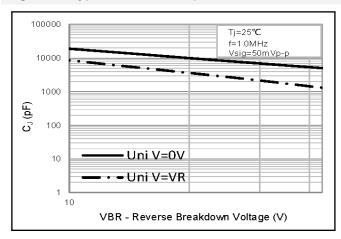
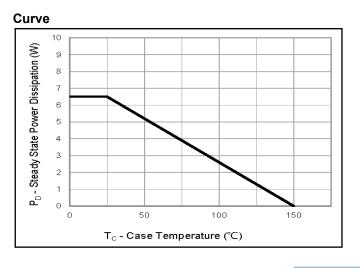
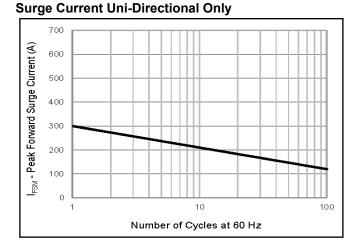


Figure 5: Steady State Power Dissipation Derating

Figure 6: Maximum Non-Repetitive Peak Forward





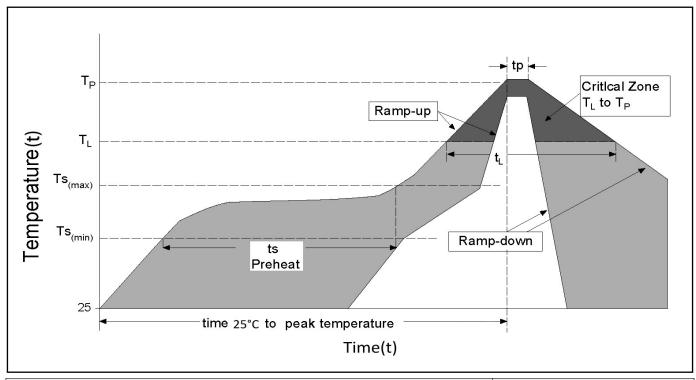
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# **Transient Voltage Suppressor**

# **Soldering Parameters**



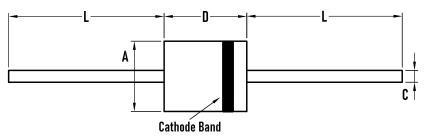
Reflow 0	Lead-free assembly		
	- Temperature Min (T <sub>S</sub> (min))	150°C	
Pre Heat	- Temperature Max (T <sub>S</sub> (max))	200°C	
	- Time (min to max) (t <sub>S</sub> )	60 - 180 secs	
Average ramp up rate (Lie	quidus Temp (T∟) to peak)	3°C/second max	
$T_{S}(max)$ to $T_{L}$ -	T <sub>S</sub> (max) to T <sub>L</sub> - Ramp-up Rate		
Reflow	- Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
Reliow	- Time (t <sub>L</sub> )	60 -150 secs	
Peak Temp	Peak Temperature (T <sub>P</sub> )		
Time within 5°C of actua	Time within 5°C of actual peak Temperature (t <sub>p</sub> )		
Ramp-do	6°C/second max		
Time 25°C to peak Temperature (t)		8 minutes Max.	
Do not	260°C		





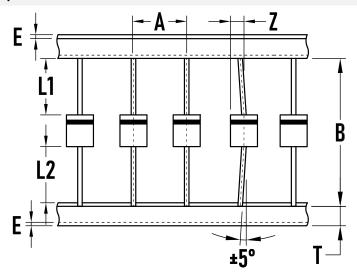
# **Transient Voltage Suppressor**

## Package Mechanical Data - P600



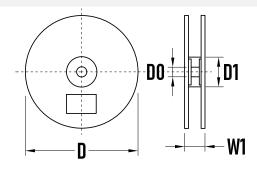
SYMBOL	Inc	hes	MILLIMETER		
STIVIDUL	MIN	MAX	MIN	MAX	
Α	0.339	0.358	8.6	9.1	
С	0.048	0.052	1.22	1.32	
D	0.339	0.358	8.6	9.1	
L	1	_	25.4	_	

# Packaging Tape-P600



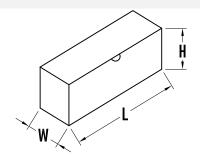
SYMBOL	Dimension(mm)
Α	10.0±0.5
В	53.0±1.0
Z	1.2Max.
Т	6.0±0.4
E	0.8Max.
L1-L2	1.0Max.

# **Packaging Reel**



SYMBOL	Dimension(mm)
D	330.0±3.0
D0	16.4±2.0
D1	86.0±2.0
W1	76.0±3.0
Quantity	800PCS

# **Packaging BOX**



SYMBOL	Dimension(mm)
L	250.0±5.0
W	75.0±5.0
Н	114.0±5.0
Quantity	300PCS

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